

Thomas - Fermi

It helps that you remember these fourier transform pairs (N.B - 3. Dimensional)

$$\frac{1}{r} \longleftrightarrow \frac{4\pi}{q^2} \quad (1)$$

$$\frac{1}{r} e^{-q_0 r} \longleftrightarrow \frac{4\pi}{q^2 + q_0^2} \quad (2)$$

Eqn 9.17 gives.

$$\delta n(q) = \frac{v_{\text{ext}}(q)}{\frac{4\pi e^2}{q^2} \left[1 + \frac{q^2}{q_{\text{TF}}^2} \right]}$$

but (1) $\Rightarrow v_{\text{ext}}(q) = \frac{-4\pi Q e}{q^2}$ (Charge $+Q$)

$$\therefore \delta n(q) = \frac{-Q/e}{(1 + q^2/q_{\text{TF}}^2)}$$

Hence (2) \Rightarrow

$$\begin{aligned} \delta \phi(r) &= \frac{-Q/e}{(2\pi)^3} \int_{-\infty}^{\infty} dq e^{i q \cdot r} \frac{q_{\text{TF}}^2}{q^2 + q_{\text{TF}}^2} \\ &\propto -\frac{Q e}{r} e^{-q_{\text{TF}} r} \end{aligned}$$

Note: (1) Perfect screening.

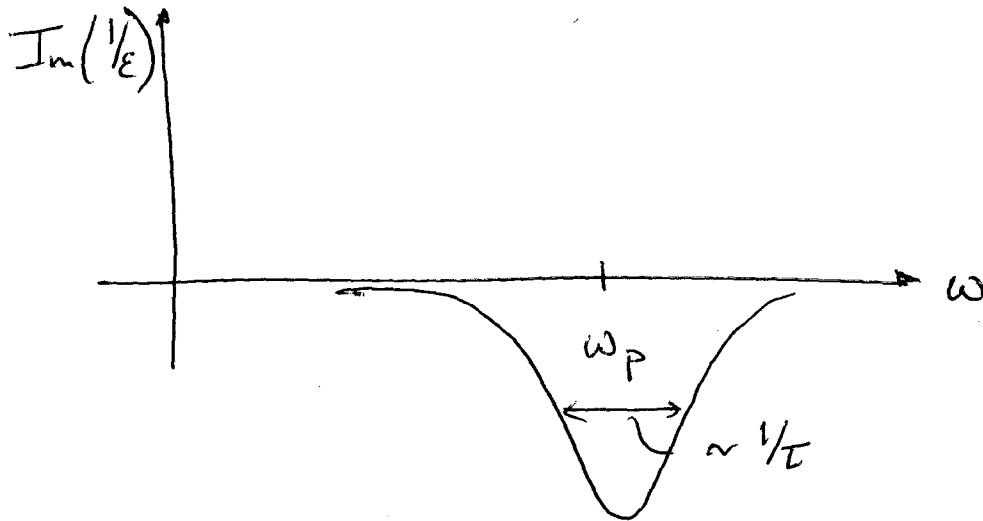
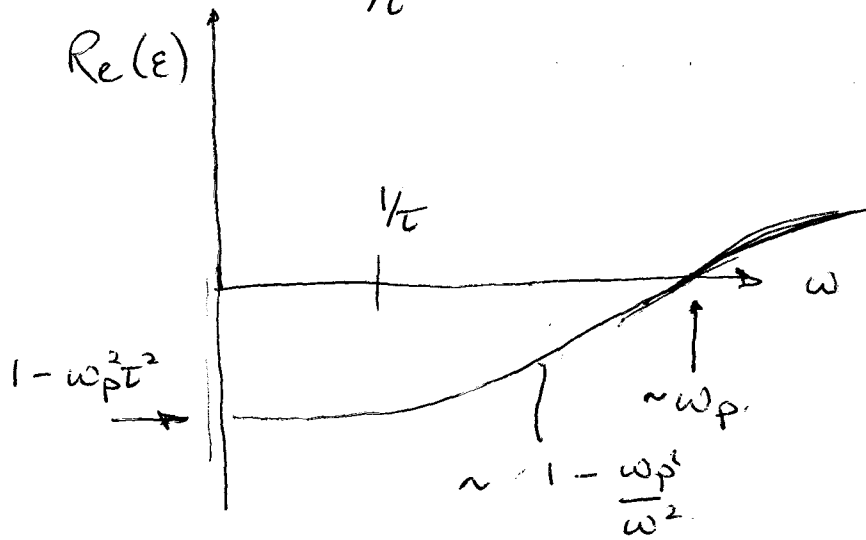
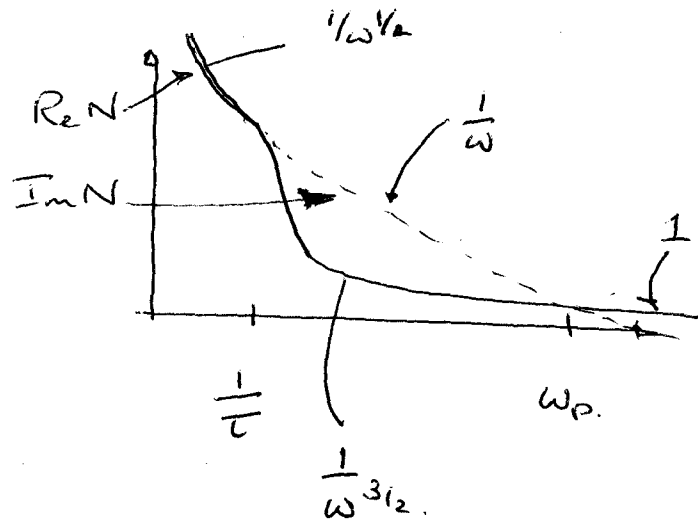
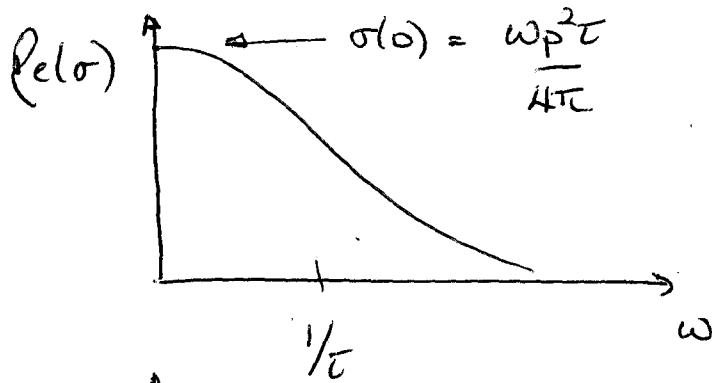
$$\int dr \delta \phi(r) = \int dr \int dq e^{i q \cdot r} \delta n(q) = \delta n(q=0) = -Q/e$$

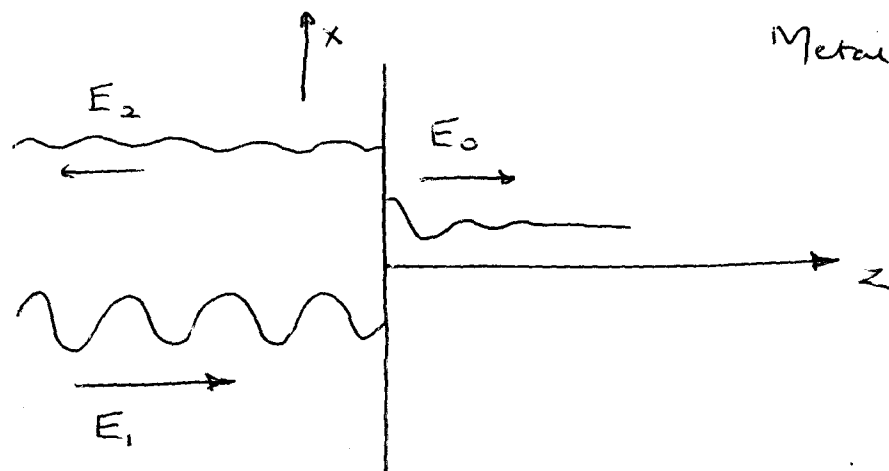
(2) Singular behaviour of δn as $r \rightarrow 0$, clearly wrong.

$$\epsilon = 1 - \frac{\omega_p^2}{\omega^2 + (i/\tau)\omega}$$

$$= 1 + \frac{4\pi\sigma i}{\omega}$$

Assume a "good" metal. $\omega_p \tau \gg 1$.





In vacuum.

$$E_x = E_1 e^{i\omega\left(\frac{z}{c} - t\right)} + E_2 e^{-i\omega\left(\frac{z}{c} + t\right)}$$

In metal.

$$E_x = E_0 e^{i\omega\left(\frac{Nz}{c} - t\right)}$$

Boundary conditions.

on E_x : $\Rightarrow E_0 = E_1 + E_2$

Determine H_y from $\nabla \times E = -\frac{\partial B}{\partial t}$ $B = \mu_0 H$.

\Rightarrow on H_y : $\Rightarrow NE_0 = E_1 - E_2$

Thus $R = \left| \frac{E_2}{E_1} \right|^2 = \left| \frac{1-N}{1+N} \right|^2$

$$N = \sqrt{\epsilon}$$

Various limits. [assume $\frac{1}{\tau} \ll \omega_p$]

(i) $\omega \ll 1/\tau$: $\epsilon \approx \frac{i\omega_p^2 \tau}{\omega} = i \frac{4\pi\sigma(\omega)}{\omega}$

So $N = (1+i) \left(\frac{2\pi\sigma(\omega)}{\omega} \right)^{1/2}$ [In S.I. $(1+i) \left(\frac{\sigma}{2\omega\epsilon_0} \right)^{1/2}$]

Since $|N| \gg 1$

$$R = \left| \frac{1 - 1/N}{1 + 1/N} \right|^2 \approx 1 - 2 \left(\frac{1}{N} + \frac{1}{N^*} \right)$$

$$= 1 - 2 \left(\frac{\omega}{2\pi\sigma} \right)^{1/2}$$

Small deviation from unity

(ii) $\frac{1}{\tau} \ll \omega \ll \omega_p$.

Here $\epsilon = 1 - \frac{\omega_p^2}{\omega^2(1 + i/\omega\tau)}$

$$\approx -\frac{\omega_p^2}{\omega^2} \left(1 - \frac{i}{\omega\tau}\right) + O(1)$$

$$\therefore N \approx i \left(\frac{\omega_p}{\omega}\right) \left(1 - \frac{1}{2} \frac{i}{\omega\tau}\right)$$

— Note that N is ~~not~~ nearly pure imaginary (which means $R \approx 1$) and $|N| \gg 1$

So as before

$$R \approx 1 - 2 \left(\frac{1}{N} + \frac{1}{N^*} \right)$$

$$\approx 1 - 2 \frac{(N + N^*)}{|N|^2}$$

$$= 1 - 2 \frac{(\omega_p/\omega^2\tau)}{(\omega_p^2/\omega^2)} = 1 - \underbrace{\frac{2}{(\omega_p\tau)}}_{\text{still small, but constant in freq.}}$$

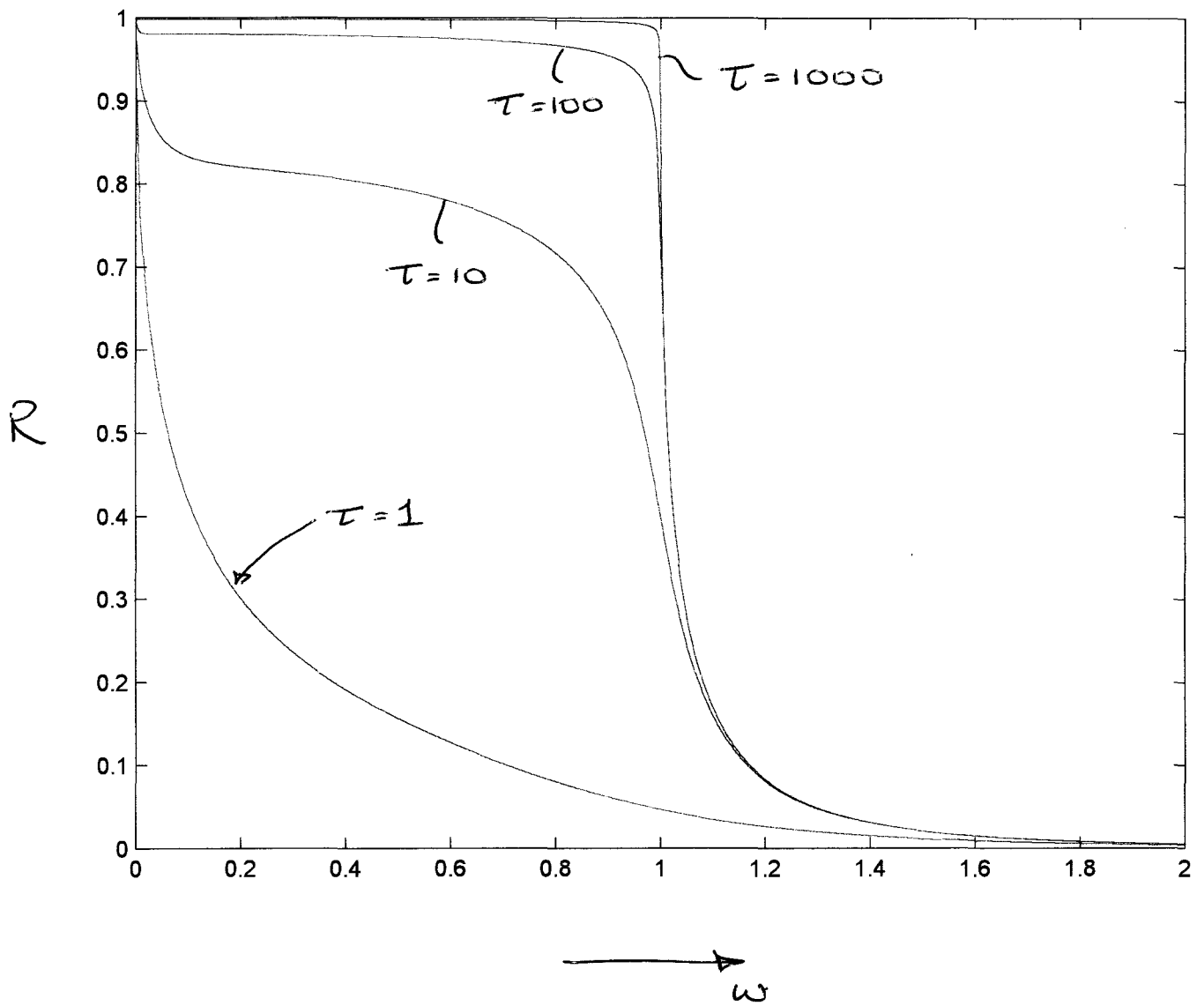
(iii) $\omega_p \ll \omega$.

Now ϵ positive, real, and close to 1

$$N \approx 1 - \frac{1}{2} \frac{\omega_p^2}{\omega^2}$$

$$R = \left| \frac{1-N}{1+N} \right|^2 \approx \left| \frac{\frac{1}{2} \frac{\omega_p^2}{\omega^2}}{2} \right|^2 \approx \frac{1}{16} \left(\frac{\omega_p}{\omega} \right)^4$$

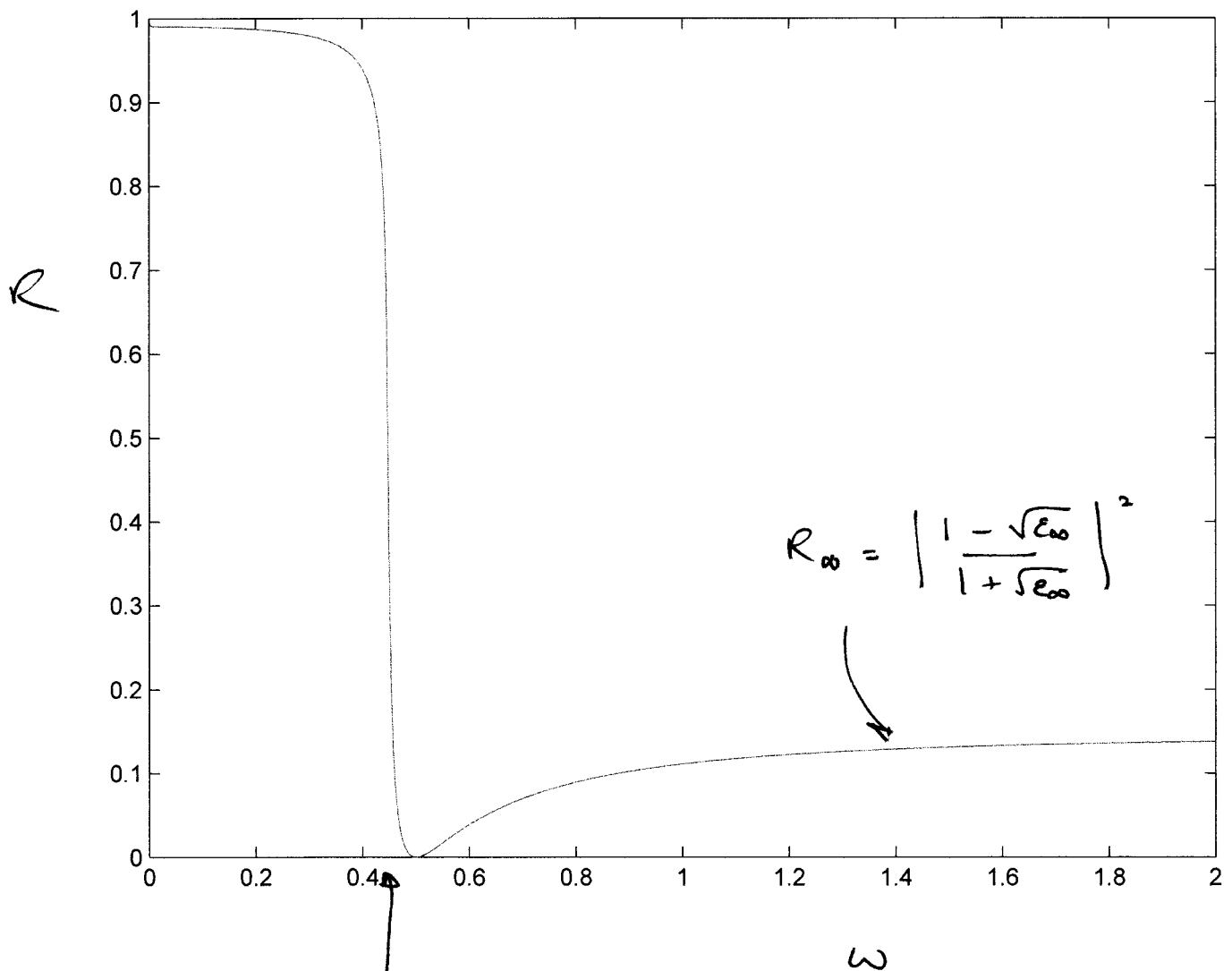
$$\omega_p = 1$$



It can be the case that the dielectric constant is not 1 at high frequencies — for example in a (metallic) doped semiconductor where

$$\epsilon = \epsilon_{\infty} - \frac{\omega_p^2}{\omega^2 + i\omega/\tau}$$

Here is a plot for $\epsilon_{\infty} = 5$, $\omega_p = 1$, $1/\tau = 0.5 \times 10^{-3}$



Plasma frequency is
actually $\frac{\omega_p^2}{\epsilon_{\infty}}$

— For discussion in supervision,
but briefly.

o Metals are shiny due to reflection

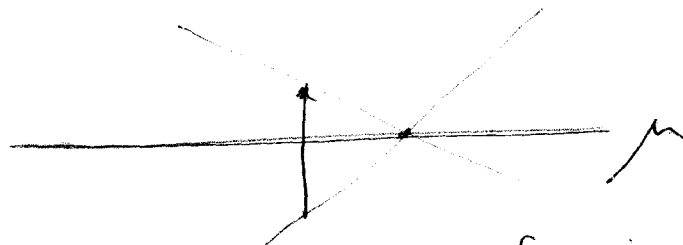
— $\epsilon < 0$; n purely imaginary

— little absorption because conductivity
is large

o Glass is transparent because there is
a gap between valence & conduction
bands

— but glass is not a periodic crystal.

o Graphite black because although a
metal, there is absorption by low energy
bands



— poor metal because fermi surface of "points"
in k -space

o Sugar is white because of scattering
of light — no absorption & little
reflection at any particular surface.

--- Include:

- Existence of Fermi surface

- Screening in metal

$$\frac{1}{r} \rightarrow e^{-q_{TF} r}$$

— in insulator $\frac{1}{r} \rightarrow \frac{1}{\epsilon r}$

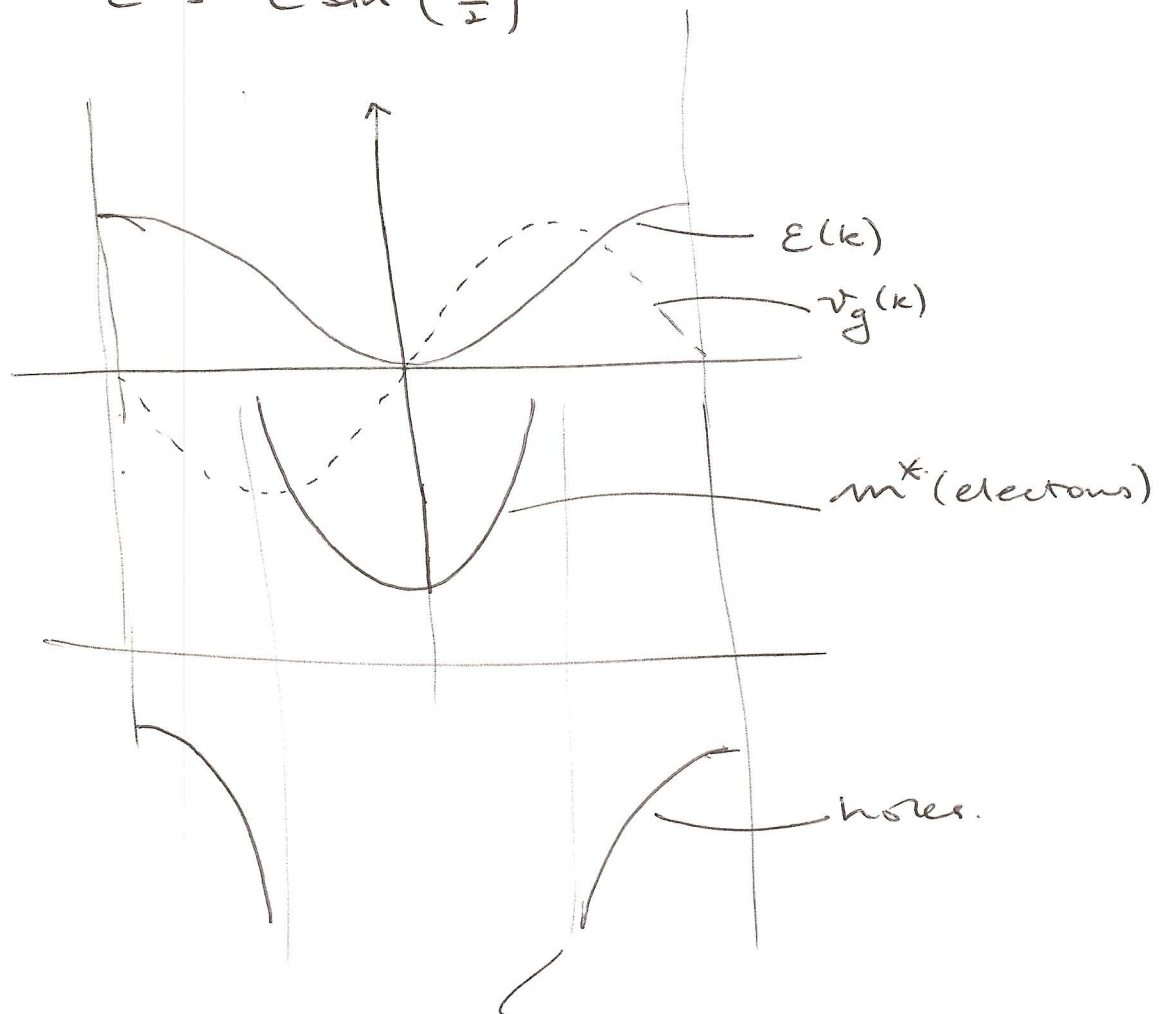
- Plasmons $\rightarrow \epsilon \sim 1 - \frac{\omega_p^2}{\omega^2}$

so $n = \sqrt{\epsilon}$ pure imaginary below plasma freq. \rightarrow good reflector

- Specific heat of a metal $\propto kT$
— good thermal & electrical conductivity

- Pauli paramagnetism (see chapter 10).

$$\mathcal{E} = C \sin^2\left(\frac{ka}{2}\right)$$



note that $\frac{1}{m^*} \propto \frac{d^2 \mathcal{E}}{dk^2}$
 — so $m^* \rightarrow \infty$ at points of inflection.

$$-eE = \hbar \dot{k} \Rightarrow k(t) = k(0) - \frac{eEt}{\hbar}$$

$$v_g = \frac{1}{\hbar} \frac{\partial \mathcal{E}}{\partial k} = \frac{Ca}{2\hbar} \sin \left[a \left(k(0) - \frac{eEt}{\hbar} \right) \right]$$

$$x(t) = \frac{C}{2eE} \cos \left[a \left(k(0) - \frac{eEt}{\hbar} \right) \right]$$

— For data in fig 9.2

$$E = V/L \quad L \approx 1 \mu\text{m}$$

$$v_{\text{Bloch}} = \frac{eV}{\hbar} \cdot \frac{a}{L}$$

fit the slope. (offsets not controlled)

$$a = L \left(\frac{\hbar}{e} \right) \frac{dv_B}{dV} \approx 15 \text{ nm.}$$

—
For GaAs.

$$\omega_{\text{Bloch}} = \frac{eFa}{\hbar} \quad a \approx 0.2 \text{ nm}$$

$$F \approx 100 \text{ Vm}^{-1}$$

$$\Rightarrow \omega_{\text{Bloch}} = 3 \times 10^7 \text{ s}^{-1}$$

$$v_{\text{Bloch}} \approx 2 \times 10^8 \text{ Hz.}$$

$$\text{Amplitude} = \frac{\text{bandwidth}}{eF} \sim \frac{10 \text{ eV}}{100 \text{ eV}} \cdot m.$$

$$\sim \underline{10^{-1} \text{ m}}$$

Much larger than any reasonable mean free path \Rightarrow electron scatters and will not conserve momentum \Rightarrow not observable.

11.23

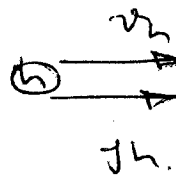
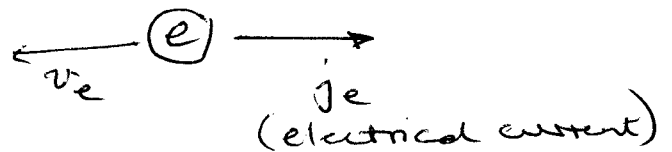
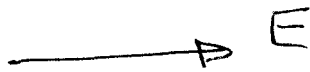
Electron: $\hbar \vec{k}_e = -eE$

Hole: $\hbar \vec{k}_h = eE$

Note that although $k_h = -k_e$

$$\varepsilon_h(k_h) = -\varepsilon_e(k_e)$$

$$\text{Thus } v_h = \frac{\partial \varepsilon_h}{\partial k_h} = \frac{\partial \varepsilon_e}{\partial k_e} = v_e$$



⇒ Same direction of electrical current
— Opposite velocity

Cyclotron resonance

$$E(k) = \frac{1}{2} \frac{\hbar^2 k^2}{m^*}$$

$$\vec{v} = \frac{1}{\hbar} \vec{\nabla}_k E(k) = \frac{\hbar \vec{k}}{m^*}$$

Equⁿ of motion

$$\hbar \dot{\vec{k}} = -e \frac{\hbar}{m^*} \vec{k} \times \vec{B}$$

$$\text{Put } \vec{B} = B \hat{z} \Rightarrow \dot{k}_z = 0.$$

$$\frac{d\vec{k}}{dt} = \frac{eB}{m^*} \hat{z} \times \vec{k}$$

\Rightarrow Circular motion with angular velocity $\omega_c = \frac{eB}{m^*}$

For a hole $e \rightarrow -e$

Sense of orbit opposite to that for electron

Equ. 11.24 can be written ($\beta = \frac{eB\tau}{m} = \omega_c\tau$)

$$v_x + \beta v_y = -\frac{e\tau}{m} E_x$$

$$-\beta v_x + v_y = -\frac{e\tau}{m} E_y$$

$$v_z = -\frac{e\tau}{m} E_z$$

$$\begin{bmatrix} 1 & \beta & 0 \\ -\beta & 1 & 0 \\ 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} v_x \\ v_y \\ v_z \end{bmatrix} = -\frac{e\tau}{m} \begin{bmatrix} E_x \\ E_y \\ E_z \end{bmatrix}$$

Note that $\begin{pmatrix} 1 & -\beta & 0 \\ \beta & 1 & 0 \\ 0 & 0 & 1+\beta^2 \end{pmatrix} \begin{pmatrix} 1 & \beta & 0 \\ -\beta & 1 & 0 \\ 0 & 0 & 1 \end{pmatrix} = \frac{1}{1+\beta^2} \begin{pmatrix} 1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1 \end{pmatrix}$

$$\therefore \begin{pmatrix} v_x \\ v_y \\ v_z \end{pmatrix} = -\frac{e\tau}{m} \cdot \frac{1}{1+\beta^2} \begin{bmatrix} 1 & -\beta & 0 \\ \beta & 1 & 0 \\ 0 & 0 & 1+\beta^2 \end{bmatrix} \begin{bmatrix} E_x \\ E_y \\ E_z \end{bmatrix}$$

$$\vec{j} = -ne \vec{v}$$

$$\therefore \sigma = \frac{ne^2\tau}{m} \cdot \frac{1}{1+\beta^2} \begin{bmatrix} 1 & -\beta & 0 \\ \beta & 1 & 0 \\ 0 & 0 & 1+\beta^2 \end{bmatrix}$$

NB. σ_{zx} indep. of field.